

# PS9661, PS9661L

# NEC's HIGH NOISE REDUCTION 25 Mbps CMOS OUTPUT TYPE 8-PIN DIP OPTOCOUPLER

#### **DESCRIPTION**

NEC's PS9661 and PS9661L are optically coupled isolators containing a GaAlAs LED on the input side and a CMOS output IC on the output side.

These photocouplers are high common mode transient immunity (CMR), high-speed CMOS output type devices, making them ideal for high-speed logic interface circuits.

The PS9661 is in a plastic DIP (Dual In-line Package) and the PS9661L is lead bending type (Gull-wing) for surface mounting.

#### **FEATURES**

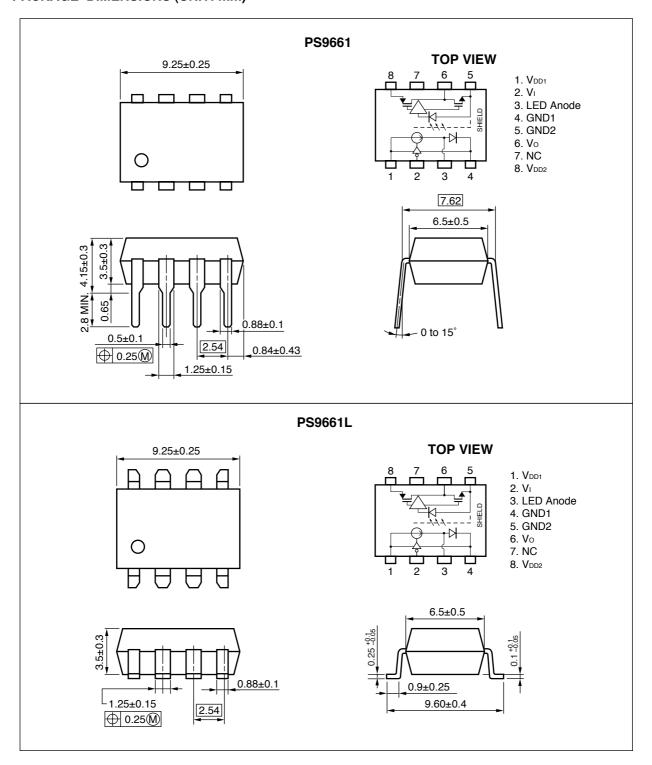
- · High-speed response (25 Mbps)
- High common mode transient immunity (CMH, CML = ±20 kV/µs TYP.)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Pulse width distortion (ItphL tpLHI = 3 ns TYP.)
- · Ordering number of tape product: PS9661L-E3, E4: 1 000 pcs/reel

#### **APPLICATIONS**

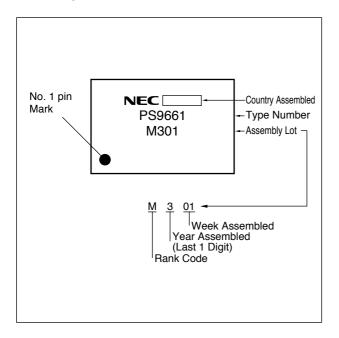
- · Factory Automation Network
- · Measurement equipment
- PDP

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## PACKAGE DIMENSIONS (UNIT: mm)



### MARKING EXAMPLE



### **ORDERING INFORMATION (Solder Contains Lead)**

Part Number	Package	Packing Style
PS9661	8-pin DIP	Magazine case 50 pcs
PS9661L		
PS9661L-E3		Embossed Tape 1 000 pcs/reel
PS9661L-E4		

### **ORDERING INFORMATION (Pb-Free)**

Part Number	Package	Packing Style		
PS9661-A	8-pin DIP	Magazine case 50 pcs		
PS9661L-A				
PS9661L-E3-A		Embossed Tape 1 000 pcs/reel		
PS9661L-E4-A				

## ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Pa	rameter	Symbol	Ratings	Unit
Diode	Input Voltage	Vı	-0.5 to V <sub>DD1</sub> +0.5	٧
Detector	Detector Supply Voltage		0 to 5.5	V
	Output Voltage	Vo	-0.5 to V <sub>DD2</sub> +0.5	٧
	Output Current	lo	10	mA
Isolation Voltage*1		BV	3 750	Vr.m.s.
Total Power Dissipation		Рт	150	mW
Operating Ambient Temperature		TA	-40 to +85	°C
Storage Temper	ature	T <sub>stg</sub>	-40 to +125	°C

<sup>\*1</sup> AC voltage for 1 minute at  $T_A = 25^{\circ}C$ , RH = 60% between input and output.

## RECOMMENDED OPERATING CONDITIONS (TA = 25°C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
High Level Input Voltage	ViH	2.0		V <sub>DD1</sub>	V
Low Level Input Voltage	VIL	0		0.8	V
Supply Voltage	V <sub>DD1</sub> , V <sub>DD2</sub>	4.5	5.0	5.5	<b>V</b>
Rise Time	<b>t</b> r			100	ns
Fall Time	<b>t</b> f				

# ELECTRICAL CHARACTERISTICS (Recommended Operating Conditions Unless Otherwise Specified. Note That $V_{DD1} = V_{DD2} = 5 \text{ V.}$ )

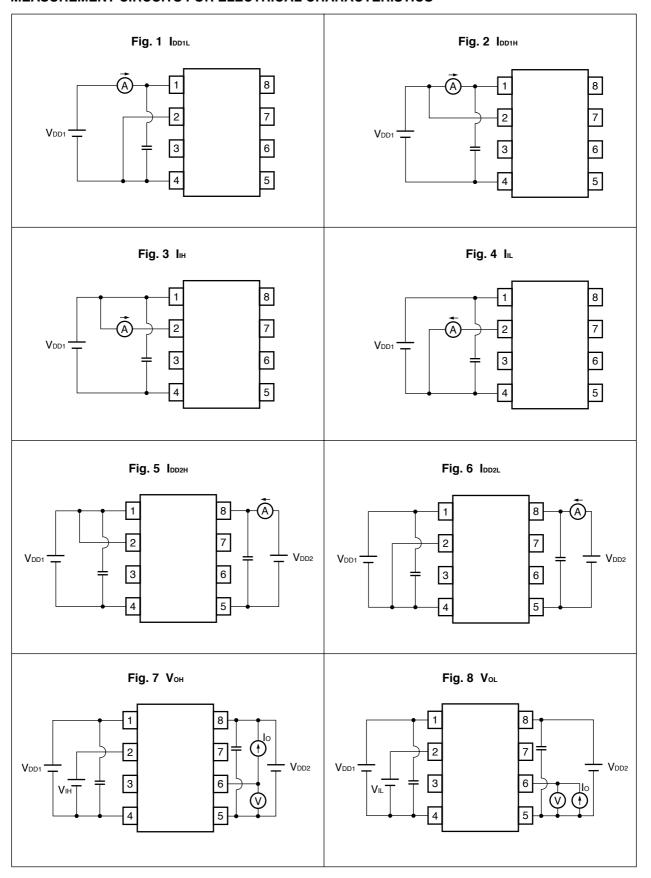
	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit	Fig.
Diode	Low Level Supply Current	I <sub>DD1L</sub>	V1 = 0 V		7.5	10.0	^	1
	High Level Supply Current	I <sub>DD1H</sub>	VI = VDD1		0.15	3.0	mA	2
	Input Current	lı	VI = 0 V or VI = VDD1	-10		10	μΑ	3, 4
Detector	Output Supply Current	I <sub>DD2H</sub>	VI = VDD1		7	9	A	5
		I <sub>DD2L</sub>	V <sub>I</sub> = 0 V		5	9	mA	6
	High Level Output Voltage	Vон	$I_0 = -20 \ \mu A, \ V_1 = V_{1H}$	4.4	5.0			7
			Io = -4 mA, Vı = Vıн	4.0	4.8		v	
	Low Level Output Voltage	Vol	Iο = 20 μA, Vι = VιL		0.01	0.1	V	8
			Io = 4 mA, Vı = VıL		0.32	1.0		
Coupled	Isolation Resistance	R <sub>I-O</sub>	V <sub>I-O</sub> = 1 kV <sub>DC</sub> , RH = 40 to 60%, T <sub>A</sub> = 25°C	10 <sup>11</sup>			Ω	
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C		1.3		pF	
	Propagation Delay Time $(H \rightarrow L)$	<b>t</b> PHL	C <sub>L</sub> = 15 pF, CMOS Signal Levels		20	40	9	9
	Propagation Delay Time $(L \rightarrow H)$	<b>t</b> PLH			23	40		
	Pulse Width	PW		40				
	Pulse Width Distortion (PWD)	трнц-трцн			3	8	ns	
	Propagation Delay Skew	<b>t</b> PSK				20		
	Rise Time	tr			9			
	Fall Time	tf			8			
	Common Mode Transient Immunity at High Level Output	СМн	$V_1 = V_{DD1} = V_{DD2} = 5V,$ $V_0 > 0.8 \ V_{DD1}, \ V_{CM} = 1 \ kV, \ T_A = 25^{\circ}C$	10	20		,	10
	Common Mode Transient Immunity at Low Level Output	CM∟	$V_1 = V_{DD1} = V_{DD2} = 5V, V_1 = 0V$ $V_0 < 0.8 \ V_{DD1}, \ V_{CM} = 1 \ kV$	10	20		kV/ <i>μ</i> s	

<sup>\*1</sup> Typical values at  $T_A = 25^{\circ}C$ 

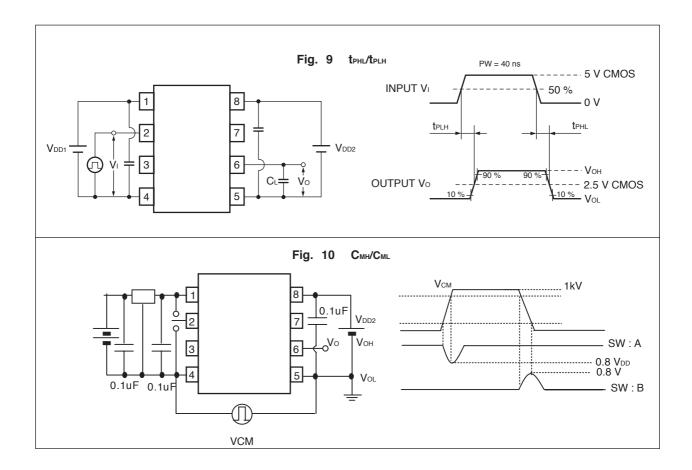
### **USAGE CAUTIONS**

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1  $\mu$ F is used between V<sub>DD</sub> and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.

## MEASUREMENT CIRCUITS FOR ELECTRICAL CHARACTERISTICS



Preliminary Data Sheet



#### Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A -AZ Not Detected (*)		
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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